ELECTRONIC SCIENCE Paper II

Time Allowed: 75 Minutes] [Maximum Marks: 100 Note: This Paper contains Fifty (50) multiple choice questions, each question carrying Two (2) marks. Attempt All questions.

- 1. For a certain 12 V zener diode, a 10 mA change in zener current produces a 0.1 V change in zener voltage. The zener impedance for this current, change is:
 - (A) 0.1 ohm
 - (B) 1 ohm
 - (C) 10 ohm
 - (D) 100 ohm
- 2. Which of the following statements is *correct*:
 - (A) more number of electron-hole pairs will be generated in silicon than in germanium at room temperature
 - (B) less number of electron-hole pairs will be generated in silicon than germanium at room temperature
 - (C) number of electron-hole pairs generated are equal both in silicon and germanium at room temperature
 - (D) Conductivity of silicon is more than that of germanium at room temperature

- - (A) Impurity diffusion
 - (B) Doping
 - (C) Epitaxy
 - (D) Ion implantation
- 4. A major factor that limits the high frequency gain of MOS transistors is.....caused by overlapping of the gate electrode and the drain.
 - (A) Overall impedance
 - (B) Parasitic capacitance
 - (C) Parasitic conductance
 - (D) Overall conductance

- 5. Metallization in IC fabrication is carried by :
 - (A) CVD technique
 - (B) EB evaporation technique
 - (C) ALD technique
 - (D) Oxidation technique
- 6. A circuit consists of two resistances R_1 and R_2 in parallel. The total current passing through the circuit is I_T , then the current passing through R_1 is :
 - (A) $\frac{R_1}{R_1 + R_2} I_T$
 - (B) $\frac{R_1 + R_2}{R_1} I_T$
 - $\text{(C)} \ \ \frac{R_2}{R_1+R_2} \, I_T$
 - (D) $\frac{I_{T}}{R_{1}[R_{1}+R_{2}]}$

- 7. Laplace transform of first derivative of a function f(t) is :
 - (A) $\frac{F(S)}{S}$
 - (B) S F(S) f(0)
 - (C) F(S) f(0)
 - (D) S F(S) S f(0)
- 8. Z-transform of $x(n) = \delta(n k)$ for

k > 0 is:

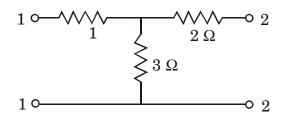
- (A) Z^K
- (B) 1
- (C) Z^{-K}
- (D) K

- 9. One of the following properties of transfer function is *correct*:
 - (A) The transfer function is not a ratio of polynomials in S
 - (B) All complex poles and zeros

 must not occur in conjugate

 pairs
 - (C) The real parts of all poles must be positive
 - (D) The coefficients of numerator $polynomial \quad P(S) \quad and$ $denominator \ polynomial \ Q(S)$ $must \ be \ real$

10. What is the driving-point impedanceof the following circuit (consider1-1 port as input) ?



- (A) 3 Ω
- (B) 5 Ω
- (C) 4Ω
- (D) 2.2Ω
- 11. The average value of a half wave rectifier voltage with a peak value of 200 V is :
 - (A) 63.7 V
 - (B) 127.3 V
 - (C) 141 V
 - (D) 0 V

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- 12. A DC voltage regulated power supply normally uses :
 - (A) only amplifier circuit
 - (B) only negative feedback
 - (C) amplifier and error feedback
 - (D) only filter circuit
- 13. Two inputs $\sin \omega t$ and $\cos \omega t$ are fed to two terminals of a differential amplifier. The output will be :
 - (A) $\sin \omega t + \cos \omega t$
 - (B) $\sin \omega t \cos \omega t$
 - (C) 0
 - (D) $\sin \omega t \cdot \cos \omega t$

- 14. For an inverting amplifier, the input is fed through a resistance R_1 and let R_2 be the feedback resistance. Then the input resistance is approximately:
 - $(A) \quad R_1^2 \, / \, R_2$
 - (B) R_2^2/R_1
 - (C) $\sqrt{R_1R_2}$
 - (D) R₁
- 15. If A is the amplifier gain and B is the feedback factor, then condition for generating oscillations is:
 - (A) AB = -1
 - (B) AB = +1
 - (C) AB = 0
 - (D) $AB = \infty$

- 16. The most suitable gate for comparing two bits is:
 - (A) AND
 - (B) OR
 - (C) NAND
 - (D) XOR
- 17. On a Karnaugh map, grouping the 0's produces:
 - (A) a product of sums expression
 - (B) a sum of products expression
 - (C) a "don't care" condition
 - (D) AND-OR logic
- 18. A 4-bit parallel adder can add:
 - (A) two 4-bit binary numbers
 - (B) two 2-bit binary numbers
 - (C) four bits at a time
 - (D) four bits in a sequence

- 19. A modulus 5 ring counter requires a minimum of :
 - (A) ten flip-flops
 - (B) five flip-flops
 - (C) four flip-flops
 - (D) twleve flip-flops
- 20. A memory with 256 addresses has:
 - (A) 256 address lines
 - (B) 6 address lines
 - (C) 1 address line
 - (D) 8 address lines
- 21. Which of the following is an example of embedded system for data communication?
 - (A) USB for mass storage
 - (B) Digital camera
 - (C) Network router
 - (D) Music player

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22.	What is the minimum number of	24.	The serial port of the standard 8051
	I/O lines required to interface a		architecture is:
	16 key matrix keyboard ?		(A) Simplex
	(A) 16	25.	(B) Half duplex
	(B) 8		(C) 'Receive' buffered
	(C) 32		(D) 'Transmit' buffered
	(D) 4		Which is the addressing mode for
23.	What is the minimum number of		the instruction MOVC A,
	interface lines required for		@ A + DPTR ?
	implementing I2C interface ? (A) 2		(A) Direct
	(B) 1		(B) Indexed
	(C) 3		(C) Immediate
	(D) 4		(D) Register

26. What will be the output of the following C program module?

main()

```
{ int i, j;
    i = 0;
    do
    {          j = i * i;
    i++;
    } while (j < = 6);
    print ("%d %d", i, j);</pre>
```

(A) 2 4

}

- (B) 3 4
- (C) 4 9
- (D) 4 4

- 27. The resolution of a SVGA monitor is:
 - (A) 320×200
 - (B) 320×400
 - (C) 640×640
 - (D) 640×480
- 28. The data structure which allows storage of multiple values in the same variable name with a subscript is called as:
 - (A) Array
 - (B) Tree
 - (C) List
 - (D) Que

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- 29. Which of the following is *not* a serial port ?
 - (A) USB
 - (B) Centronix port
 - (C) RS232 C
 - (D) 9 pin D connector on a PC motherboard
- 30. The correct sequence for file handling in C is:
 - (A) Define file pointer, use fopen, read/write data, close
 - (B) Use fopen, define file pointer, read/write data, close
 - (C) Use fopen, close, define file pointer, read/write data
 - (D) Define file pointer, read/write data use fopen, close

- 31. A transmission line has a VSWR of2, The reflection coefficient is :
 - (A) $\frac{1}{3}$
 - (B) 0
 - (C) $\frac{1}{4}$
 - (D) $\frac{1}{2}$
- 32. A strip transmission line is formed over a dielectric medium with $\epsilon_r = 4$. The width of the strip is 6 mm and the thickness of dielectric is 2 mm. The characteristic impedance of this line is :
 - $(A) \quad \frac{1}{20} \, \sqrt{\frac{\mu_0}{\varepsilon_0}}$
 - (B) $\sqrt{\frac{\mu_0}{\epsilon_0}}$
 - $(c) \ 2 \sqrt{\frac{\mu_0}{\varepsilon_0}}$
 - $(D) \ \frac{1}{10} \sqrt{\frac{\mu_0}{\varepsilon_0}}$